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INFORMATI	ON DISCLOSURE STATEMENT		Applicant: Shunpei Y	AMAZAKI, et	t al.				
(Use several sheets if necessary)			Filing Date: February 12, 1997		Group: 2822				
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mw	5,608,232	03/04/97	YAMAZAKI ET AL.		/				
mw	5,608,251	03/04/97	KONUMA ET AL.	+					
Thu	5,620,095	04/15/97	KONUMA ET AL.	 					
mul	5,639,698	06/17/97	YAMAZAKI ET AL.	+	X	L			
mul	4,151,058	04/24/79	KAPLAN	+/					
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Thui	01-128446	05/22/89	JAPAN			Yes No ABST.			
MU	02-257619	10/18/90	JAPAN			ABST.			
mu,	04-206532	07/28/92	JAPAN			ABST.			
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INFORMATION DISCLOSURE STATEMENT JUL 1 7 2000 Applicant: Shunpei YAMAZAKI, et al.								
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mw mw		4,405,435	09/20/83	TATEISHI ET AL.				
mw	 	4,498,416	02/12/85	BOUCHAIB	 	/		
mw		4,503,807	03/12/85	NAKAYAMA ET AL.		ř I		
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mu		4,557,036	12/10/85	KYURAGI ET AL.	+/-	\vdash		
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Thw		4,951,601	08/28/90	MAYDAN ET AL.			
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Thw	5,294,811	03/15/94	AOYAMA ET AL.			
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